

RoHS

Halogen

Device Specification

ELECTRICAL CHARACTERISTICS

							-			
	Part Number		I _{trip} (A)	V _{max} (Vdc)	I _{max} (A)	P _{d typ} (W)	Maximum Time To Trip		Resistance	
		I _{hold} (A)					Current (A)	Time (Sec.)	R _{min} (Ω)	R _{1max} (Ω)
	PTC18128V110	1.10	2.20	8	100	0.80	8.00	0.30	0.040	0.210

Note: I_{hold} = Hold current: maximum current device will pass without tripping in 23°C still air.

I_{trip} = Trip current: minimum current at which the device will trip in 23°C still air.

V_{max} = Maximum voltage device can withstand without damage at rated current (I_{max})

I_{max} = Maximum fault current device can withstand without damage at rated voltage (V_{max})

 $P_{d typ}$ = Typical power dissipated from device when in the tripped state at 23 °C still air.

R_{min} = Minimum resistance of device in initial (un-soldered) state.

R_{1max} = Maximum resistance of device at 23°C measured one hour after tripping or reflow soldering of 260°C for 20 sec.

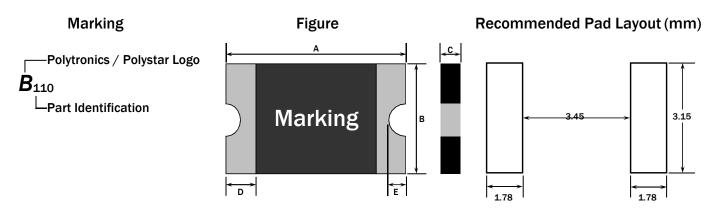
*Value specified were determined using the PWB with 0.030"*1.5oz copper traces.

*Customer should verify the device performance in their specified conditions.

Caution: Operation beyond the specified rating may result in damage and possible arcing and flame.

Recognitions: TÜV lus





Note: Polystar is Polytronics's manufacturing site in China. The Polystar ID marking shall appear on smallest package.

PHYSICAL DIMENSIONS (mm)

Part Number	Α		В		С		D		E	
	Min.	Max.								
PTC18128V110	4.37	4.73	3.07	3.41	0.30	0.71	0.30	1.20	0.15	0.65

OSpecifications are subject to change without notice.